

Heterostructure Engineering of a Reverse Water Gas Shift Photocatalyst

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To achieve substantial reductions in CO₂ emissions, catalysts for the photoreduction of CO₂ into value-added chemicals and fuels will most likely be at the heart of key renewable-energy technologies. Despite tremendous efforts, developing highly active and selective CO₂ reduction photocatalysts remains a great challenge. Herein, a metal oxide heterostructure engineering strategy that enables the gas-phase, photocatalytic, heterogeneous hydrogenation of CO₂ to CO with high performance metrics (i.e., the conversion rate of CO₂ to CO reached as high as 1400 μmol g cat⁻¹ h⁻¹) is reported. The catalyst is comprised of indium oxide nanocrystals, In₂O_{3-x}(OH)_y, nucleated and grown on the surface of niobium pentoxide (Nb₂O₅) nanorods. The heterostructure between In₂O_{3-x}(OH)_y nanocrystals and the Nb₂O₅ nanorod support increases the concentration of oxygen vacancies and prolongs excited state (electron and hole) lifetimes. Together, these effects result in a dramatically improved photocatalytic performance compared to the isolated In₂O_{3-x}(OH)_y material. The defect optimized heterostructure exhibits a 44-fold higher conversion rate than pristine In₂O_{3-x}(OH)_y. It also exhibits selective conversion of CO₂ to CO as well as long-term operational stability.

Global energy demands and climate change have stimulated intense research on the sustainable transformation of greenhouse gas CO₂ to chemicals and fuels.^[1-6] Among various approaches that enable these CO₂ conversions, of particular interest is the gas-phase solar powered heterogeneous catalytic reduction of CO₂ to CO, dubbed the photocatalytic reverse water gas shift reaction. This process can enable very high CO₂ conversion rates, and is compatible with existing chemical and petrochemical industry infrastructure, implying that it can be easily scaled, integrated, and commercialized.^[7] Key to achieving the practical implementation of this promising renewable-energy technology is to develop efficient, robust, and scalable photocatalysts for the hydrogenation of CO₂. Despite tremendous efforts, it remains a

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great challenge since the CO₂ molecule is fully oxidized and extremely stable.

Recently, semiconducting metal oxides have been widely investigated as photocatalysts for CO₂ hydrogenation mainly because of their photochemical stability. However, limited by their performance, much effort has been devoted to enhancing their photocatalytic activity.^[8–12] In this context, Indium oxide is one of the most widely used, n-type transparent conducting metal oxides in electronic, optoelectronic, and optical devices due to its large optical bandgap, low electrical resistivity, and excellent photostability.^[13] Our group has recently reported that indium oxide, In₂O_{3-x}(OH)_y, with engineered oxygen vacancy (electron trapping) and hydroxide (hole trapping) defects, is active for the photocatalytic hydrogenation of CO₂ to CO.^[14,15] The CO₂ conversion rate to CO however is at best 33.3 μmol g cat⁻¹ h⁻¹, which is too low for its practical implementation in a CO₂ refinery.

Herein, we show that heterostructure engineering of In₂O_{3-x}(OH)_y with other metal oxide semiconductor can dramatically improve its photocatalytic activity. By this means, the CO₂ to CO conversion rate was boosted from 33.3 μmol g cat⁻¹ h⁻¹ for pristine In₂O_{3-x}(OH)_y to as high as 1400 μmol g cat⁻¹ h⁻¹ for heterostructure engineered In₂O_{3-x}(OH)_y, a remarkable enhancement factor of 44-fold. Such a dramatic enhancement in conversion rate is a rare event.^[16,17] Furthermore, the heterostructure engineered In₂O_{3-x}(OH)_y exhibited excellent long-term, operational photochemical durability.

The heterostructure between the two semiconductors In₂O_{3-x}(OH)_y and Nb₂O₅ nanorods (Figure S1, Supporting Information) was constructed by a facile, two-step process (Figure 1a). First, the In(OH)₃@Nb₂O₅ precursor was prepared by growth of In(OH)₃ on Nb₂O₅ in an ethanol/water mixture. Second, the desired In₂O_{3-x}(OH)_y@Nb₂O₅ heterostructure was formed by thermally induced dehydroxylation of In(OH)₃@Nb₂O₅ at 250 °C in air for a predetermined time. To understand the physical and chemical properties of heterostructure engineered In₂O_{3-x}(OH)_y, we prepared pristine In₂O_{3-x}(OH)_y as a control reference sample. The synthetic procedure for making pristine In₂O_{3-x}(OH)_y is similar to In₂O_{3-x}(OH)_y@Nb₂O₅, except there is no Nb₂O₅ involved in the preparation process.

Thermogravimetric analysis showed that the behavior of supported In(OH)₃ in In(OH)₃@Nb₂O₅ is similar to In(OH)₃ alone (Figures S2 and S3, Supporting Information). One observes a sharp weight loss after the temperature reached ≈200 °C, accompanied by an endothermic peak at ≈240 °C, which corresponds to the conversion of cubic In(OH)₃ into cubic, defect-laden bixbyite In₂O_{3-x}(OH)_y through controlled dehydroxylation of the number of hydroxyl groups with concomitant loss of water. A set of three different In₂O_{3-x}(OH)_y@Nb₂O₅ heterostructure samples were fabricated from the corresponding precursor In(OH)₃@Nb₂O₅ (Figure S4, Supporting Information). These samples are denoted S1–S4, where the label 1–4 refers to samples with gradually increasing In₂O_{3-x}(OH)_y content. The amount of In₂O_{3-x}(OH)_y in S1–S4 were 9.79%, 15.49%, 23.21%, and 30.7%, respectively, as quantified by inductively coupled plasma-atomic emission spectroscopy. For comparison, a physically blended mixture of nanocrystalline In₂O_{3-x}(OH)_y and Nb₂O₅ nanorods was also prepared with the content of

In₂O_{3-x}(OH)_y in the mixture adjusted to be identical with that in S3.

Powder X-ray diffraction (PXRD) peaks of In₂O_{3-x}(OH)_y@Nb₂O₅, pristine In₂O_{3-x}(OH)_y, and Nb₂O₅ are shown in Figure 1b, all of the peaks of In₂O_{3-x}(OH)_y in S1–S4 were matched well with pristine In₂O_{3-x}(OH)_y, indicating that the In₂O_{3-x}(OH)_y@Nb₂O₅ are successfully prepared after calcining the precursor of In(OH)₃@Nb₂O₅, at the right temperature for the appropriate time. To explore the effect of the heterostructure on the electronic structure of In₂O_{3-x}(OH)_y, X-ray photoelectron spectroscopy (XPS) of the S3, pristine In₂O_{3-x}(OH)_y, and the physical mixture were conducted (Figure 1c, and Figure S5, Supporting Information). The In 3d core level spectra of pristine In₂O_{3-x}(OH)_y and the physical mixture show two peaks located at 442.8 and 450.3 eV, which are attributed to the characteristic spin-orbit split 3d_{5/2} and 3d_{3/2}, respectively. Interestingly, the 3d_{5/2} and 3d_{3/2} peaks of In₂O_{3-x}(OH)_y in the S3 sample are shifted toward higher binding energy, located at 443.3 and 450.9 eV, respectively (Figure 1c). This indicates an increase in effective positive charge of the In sites as a result of the heterostructure engineering. The increased population of coordinately unsaturated In sites arising from the larger population of oxygen vacancies seen in the O1s photoemission spectra in In₂O_{3-x}(OH)_y can be related to the enhanced binding energy. This point was further supported by XPS analysis of O species in these samples. Considering the content of In₂O_{3-x}(OH)_y in S3 and physical mixture samples is identical, we compared the oxygen vacancy [O] concentrations in the two samples. As shown in Figure 1d,e, the population of [O] in the S3 was 20.9%, which is higher than that in physical mixture sample (16.6%) (Figure S6, Supporting Information). Later in this article, we demonstrate that such an increase of oxygen vacancies in heterostructure engineered In₂O_{3-x}(OH)_y enhances the population and lifetime of photoexcited electron-hole pairs and as a result provides a boost to the photocatalytic activity.^[18,19]

We took S3 sample as representative to examine its morphology and chemical heterostructure using high resolution transmission electron microscopy (HRTEM). From Figure 2a, In₂O_{3-x}(OH)_y nanocrystals with a diameter of ≈4 nm, uniformly distributed on the surface of Nb₂O₅, are observable. It is noted that the use of ammonia rather than urea as the base hydrolysis source in the synthesis, proved unable to produce heterostructures of In₂O_{3-x}(OH)_y and Nb₂O₅. Instead, only two separate normal phases of In₂O_{3-x}(OH)_y and Nb₂O₅ resulted (Figure S7, Supporting Information). This observation demonstrates the importance of the controlled nucleation and growth process for making heterostructured In₂O_{3-x}(OH)_y@Nb₂O₅ by using the strategy of slow release of base by the decomposition of urea at 80 °C. The HRTEM data show well-defined heterojunctions between nanocrystalline In₂O_{3-x}(OH)_y and Nb₂O₅ nanorods (Figure 2b). Analysis of the In₂O_{3-x}(OH)_y nanocrystals on the Nb₂O₅ nanorods in the HRTEM image reveals a lattice spacing of 4.03 Å corresponding to the (211) plane. Figure 2c–f shows the scanning transmission electron microscopy (STEM) image and corresponding elemental mappings of Nb, In, and O, respectively. It can be clearly seen that In₂O_{3-x}(OH)_y was uniformly dispersed on the surface of

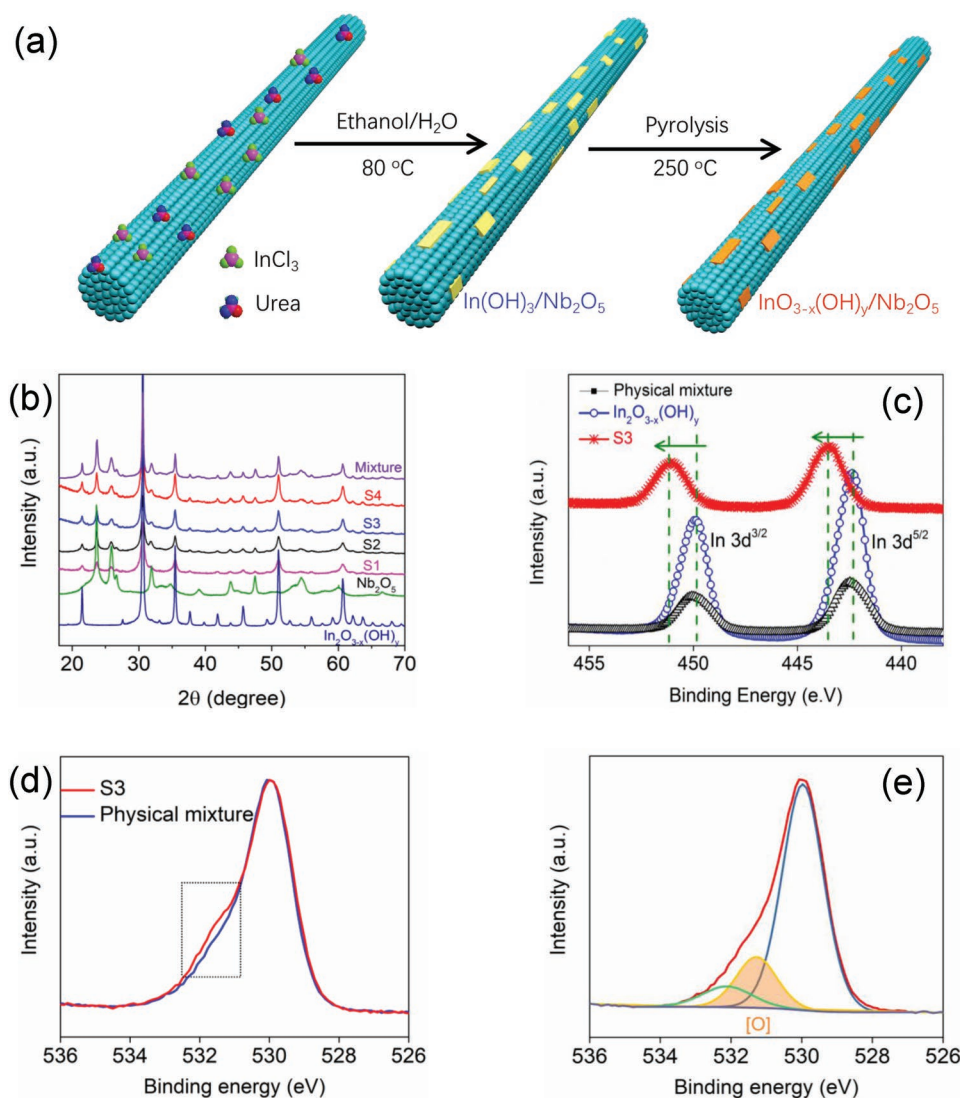


Figure 1. a) Illustration of the synthesis of $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ nanocrystals grown on the surface of Nb_2O_5 nanorods. b) PXRD patterns of pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ and Nb_2O_5 , a chemical heterostructure $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$. c) XPS and curve fitting for the $\text{In } 3d_{5/2}$ and $\text{In } 3d_{3/2}$ core level, spin-orbit split binding energies of pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$, a physical mixture $\text{In}_2\text{O}_{3-x}(\text{OH})_y/\text{Nb}_2\text{O}_5$ and a representative chemical heterostructure $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$, S3 sample. d) O 1s XPS spectrum of S3 and physical mixture sample. e) Deconvolution of the high-resolution O1s XPS spectrum of the S3 sample. The main peak at 530.3 eV is attributed to indium oxide. The two additional shoulder peaks at 531.7 and 532.5 eV are attributed to oxygen vacancies in the structure and surface OH groups, respectively.

Nb_2O_5 nanorod, a favorable requirement for optimized catalytic activity.

All samples exhibited a mesoporous structure (Figure S8, Supporting Information), and the Brunauer–Emmett–Teller (BET) specific surface areas of Nb_2O_5 , S1, S2, S3, and S4 are 84.6, 63.7, 60, 88.8, and 96.6 $\text{m}^2 \text{g}^{-1}$, respectively, were lower than that of pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ (117 $\text{m}^2 \text{g}^{-1}$) (Figure S9 and Table S1, Supporting Information). Noted also, is that the BET surface areas of S1 and S2 are lower than that of Nb_2O_5 . This can best be explained by the fact that nanocrystalline $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ grown within the mesopores of Nb_2O_5 nanorods, decreases the BET surface areas of S1 and S2 compared to Nb_2O_5 . With further increase of the content of $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ in S3, the mesoporous structure of $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ improves their surface areas. This result, together with those from the TEM observations can

explain the growth process of $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ nanocrystal on the surface of Nb_2O_5 to form heterostructures. First, the indium chloride and urea were adsorbed in the mesopores of Nb_2O_5 . Second, $\text{In}(\text{OH})_3$ precursor forms and anchors to the surface of Nb_2O_5 concomitant with the decomposition of urea to NH_3 at 80 °C. Finally, $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ nanocrystals form on the surface of Nb_2O_5 nanorods during the dehydroxylation process at 250 °C.

The mesoporous structure of the as-synthesized photocatalysts (Figure 3a) is advantageous for fast diffusion of CO_2 to catalytic centers thereby improving their performance. Photocatalytic activity was measured using the as-synthesized samples deposited on borosilicate filter films (Figure 3b). To ensure the products did not originate from adventitious carbon residues in our samples, isotope labeled $^{13}\text{CO}_2$ authenticated the origin of the products of the reduction reaction.

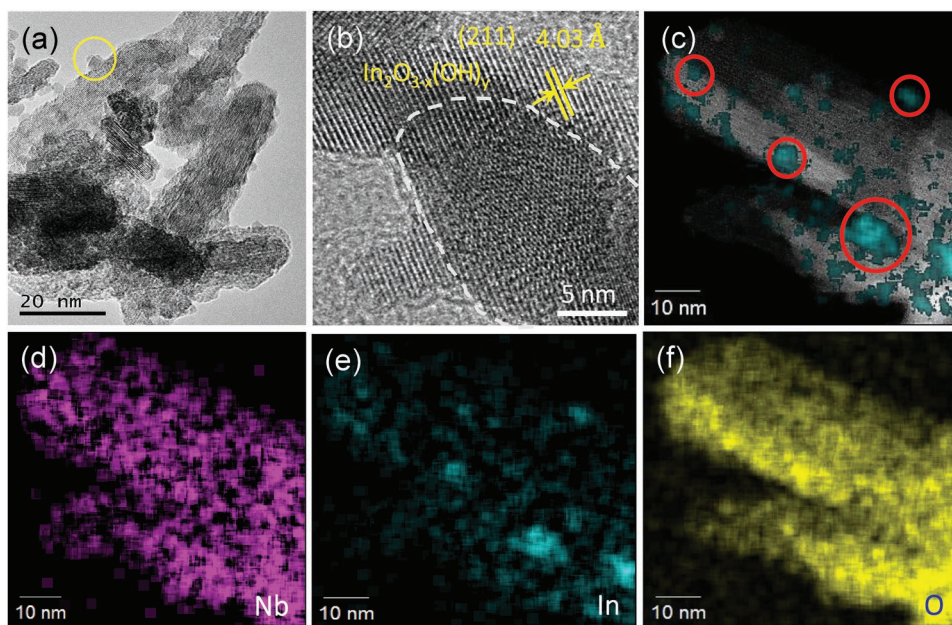


Figure 2. a) Low-resolution TEM image of S3. Yellow circle indicates that $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ nanocrystal with a diameter of ≈ 4 nm was grown on the surface of Nb_2O_5 nanorod. b) HRTEM images of S3. c–f) STEM image and corresponding EFTEM elemental (Nb, In, O) mapping.

We observed a remarkable enhancement of the hydrogenation rate of CO_2 to CO on passing from S1 to S3 (Figure 3c), reaching as high as $1400 \mu\text{mol g cat}^{-1} \text{h}^{-1}$ for S3, which then decreases for S4. This can be explained by the fact that there is more isolated $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ in S4 rather than heterostructures of $\text{In}_2\text{O}_{3-x}(\text{OH})_y/\text{Nb}_2\text{O}_5$. The product is completely ^{13}C labeled ^{13}CO without impurities (Figure S10, Supporting Information),

demonstrating high selectivity of our photocatalysts for solar powered hydrogenation of CO_2 to CO .

Note that Nb_2O_5 is highly inactive under these photocatalytic-operating conditions, showing no activity toward CO_2 to CO reduction. We also showed there is no CO produced in the dark, confirming the photocatalytic nature of the samples. It is observed that the hydrogenation rate of CO_2 to CO over

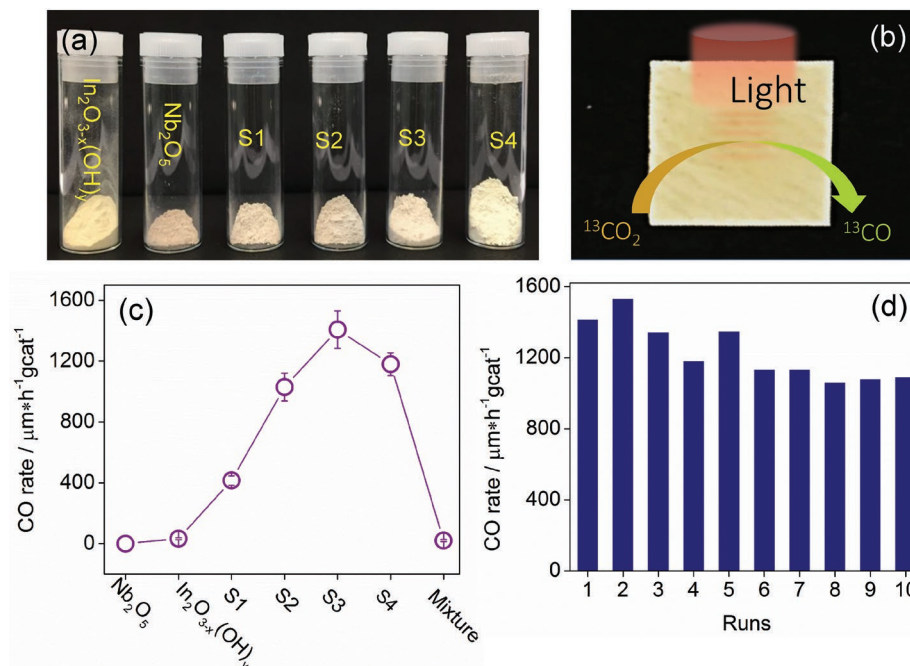


Figure 3. a) Digital photographs of as-prepared pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$, S1–S4, and Nb_2O_5 . b) Digital photograph of S3 sample deposited on borosilicate filter film for photocatalytic measurement. c) Photocatalytic performance of the listed materials. d) Long-term photocatalyst stability measurements of the S3 sample.

pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ and their physical mixture are only 33 and 21 $\mu\text{mol g}_{\text{cat}}^{-1} \text{h}^{-1}$ respectively under the same conditions, much lower than that of the heterostructured samples. These observations strongly support the proposition that heterostructure engineering of photocatalysts described herein provides a new and effective strategy for enhancing the performance of gas-phase heterogeneous CO_2 hydrogenation.

The key for practical applications is the long-term stability of a photocatalyst. As shown in Figure 3b, stability testing of S3 for photocatalytic hydrogenation of CO_2 to CO showed no decay even after 10 cycles, which involved continuous operations for 40 h. This result confirms that heterostructured $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ is stable under operating conditions employed in this study.

In metal oxides, both bulk and surface oxygen vacancies can act as traps for photoexcited electrons, while surface hydroxyl groups can function as traps for photoexcited holes.^[20] Efficient electron–hole pair separation is a prerequisite for high performance photocatalysis, and a reaction must have sufficient time to occur before recombination to the electronic ground state. To delve more deeply into the effect of heterostructure engineering on electron–hole separation efficiency, transient state surface photovoltage (TSPV) measurements were undertaken. Details of these TSPV experiments are included in the Supporting Information. We used two different excitation energies corresponding to above bandgap (355 nm) and near-bandgap (532 nm) excitation to understand how photoexcited charge carriers with different energies interact with the defect states available within the samples. The TSPV spectra measured in air are in Figure 4. They depict the photovoltage responses to be positive for all samples under pulsed laser excitation at 355 nm (Figure 4a) and 532 nm (Figure S11, Supporting Information).

The results obtained under ambient conditions indicate that adsorbed O_2 on the surface of the samples capture photo-generated electrons, while the photogenerated holes preferentially diffuse to the collector electrode surface.^[21] Noticeably, S3 exhibits a much higher photovoltage compared to the other samples, indicating that more holes accumulate on the surface of $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$ with a noticeably longer lifetime of ≈ 3 ms. As mentioned earlier, XPS results for the core level oxygen demonstrate that heterostructured $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$ creates more oxygen vacancies than pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$.

Thus, the larger population of oxygen vacancies in $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ for S3 capture the photogenerated electrons, while the holes are captured by the hydroxide, thus enhancing electron–hole separation efficiency and photocatalytic activity.

Additional evidence for the enhanced electron–hole separation efficiency of S3 seen by transient state surface photovoltage measurements derives from time-resolved fluorescence spectroscopy measurements of S3, also shown in Figure 4b. The peak of the steady-state fluorescence of S3 is located at 410 nm (Figure S12, Supporting Information). This emission is associated with the recombination of the photogenerated hole trapped at mid-gap hydroxide defects with the photogenerated electron trapped at sub-bandgap O vacancy defects in $\text{In}_2\text{O}_{3-x}(\text{OH})_y$.^[22] The radiative lifetime was extracted by exponential fitting using the Levenberg–Marquardt method:^[23] $\gamma(t) = \gamma_0 + A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2)$, where τ_1 and τ_2 are the decay times, of the time-resolved fluorescence decay curves for S3 (τ_1 and τ_2 are 0.38 and 4.05 ns, respectively), which are longer than in pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ (τ_1 and τ_2 are 0.35 and 3.12 ns, respectively). These results provide additional evidence for enhanced electron–hole separation in the heterostructure $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$.

At the interface between the $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ and Nb_2O_5 semiconductors, one expects charge-transfer and the formation of a space charge region to occur as the Fermi level is equilibrated across the sample. This electronic structure model is substantiated by measurement of the Fermi levels of S3, pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ and Nb_2O_5 nanorods at -4.03 , -3.84 , and -4.46 eV, respectively, by means of ultraviolet photoelectron spectroscopy, UPS (Figure S13, Supporting Information). The UPS results provide evidence for an electronic band model in which electrons flow from Nb_2O_5 to $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ across the heterostructure in S3. The heterojunction alignment whereby electrons flow from Nb_2O_5 to $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ is also confirmed through band alignment calculations (Figure S14, Supporting Information). Oxygen vacancies formed in the heterostructures of $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$ in S3 serve as reservoirs for photoexcited electrons, while the hydroxides act as reservoirs for photoexcited holes. The real space separation of the charge carriers stabilizes the photoexcited state, resulting in longer carrier lifetimes in $\text{In}_2\text{O}_{3-x}(\text{OH})_y@ \text{Nb}_2\text{O}_5$ that provide a significant boost in photocatalytic activity for the solar powered reverse water gas shift reaction $\text{CO}_2 + \text{H}_2 \rightarrow \text{CO} + \text{H}_2\text{O}$.

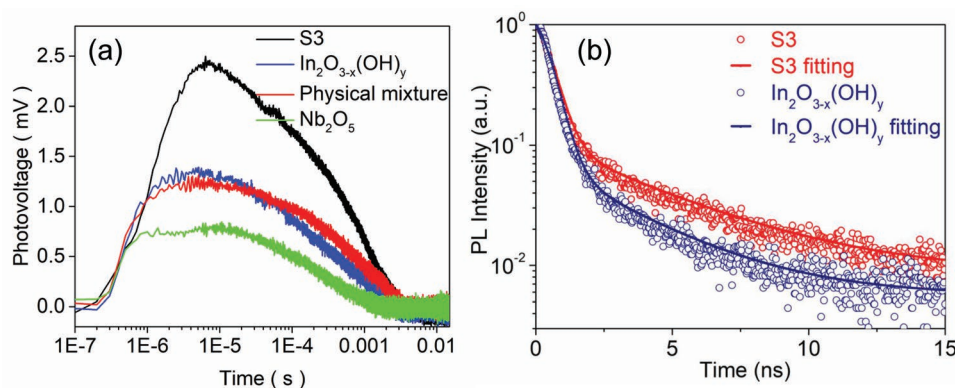


Figure 4. a) Transient state surface photovoltage responses of S3, pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$, and a physical mixture of $\text{In}_2\text{O}_{3-x}(\text{OH})_y$ and Nb_2O_5 nanorods, using 355 nm laser excitation. b) Fluorescence decay temporal profiles measured and fit for S3 and pristine $\text{In}_2\text{O}_{3-x}(\text{OH})_y$.

From a scientific perspective, challenges remain in the quest to understand how heterostructures between metal oxide semiconductors control photocatalytic performance. These challenges include disentangling the effects of heterostructure interfaces and interfacial charge transfer on defect populations; how these affect the lifetimes of photoexcited electron-hole pairs; the effect on the acidity and basicity of surface frustrated Lewis pairs, and their corresponding activity toward the hydrogenation of carbon dioxide. In terms of practical applications, significant improvements in conversion and energy efficiency together with a techno-economic life cycle assessment will be required before the class of photocatalysts described in this paper is ready for engineering a pilot scale solar fuels process.

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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Conflict of Interest

The authors declare no conflict of interest.

Keywords

charge transfer, CO₂ conversion, heterostructures, photocatalysts, semiconductors

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